



3.3V, Hot Insertion, 20-Bit, 2-Port Bus Switch

Product Features

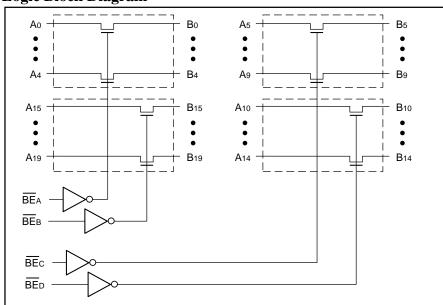
- · Near-zero propagation delay
- 5Ω switches connect inputs to outputs
- · Direct bus connection when switches are ON
- Ultra-low quiescent power 32X384 (0.2µA typical)
 - Ideally suited for notebook applications
- Fast Switching Speed 4.5ns max.
- · Permits Hot Insertion
- TTL compatible control of input levels
- · Packages available:
 - 48-pin 150-mil wide plastic BQSOP (B)

Product Description

Pericom Semiconductor's PI3B series of BusSwitch circuits are produced using the Company's advanced submicron CMOS technology, achieving industry leading performance.

The PI3B32X384 is a 3.3V, 20-bit bus switch designed with a low ON resistance allowing inputs to be connected directly to outputs. The bus switch creates no additional propagational delay or additional ground bounce noise. The switches are turned ON by the Bus Enable (\overline{BE}) input signal. Four bus enable signals are provided, one for each of the upper and lower five bits of the two 10-bit buses.

Logic Block Diagram



Truth Table(1)

Function	BEA	<u>BE</u> B	B4-B0	B19-B15
Disconnect	Н	Н	Hi-Z	Hi-Z
Connect	L	Н	A4-A0	Hi-Z
Connect	Н	L	Hi-Z	A19-A15
Connect	L	L	A4-A0	A19-A15
Function	BE C	BE D	B9-B5	B14-B10
Disconnect	Н	Н	Hi-Z	Hi-Z
Connect	L	Н	A9-A5	Hi-Z
Connect	Н	L	Hi-Z	A14-A10
Connect	L	L	A9-A5	A14-A10

Note:

1.H = High Voltage Level L = Low Voltage Level Hi-Z = High Impedance

Product Pin Configuration

	migui	*****	
= -	$\overline{}$		1/00
BEA 🛚 1	\cup	48 🛚	VCC
B0 ☐ 2		47	B19
A0 ☐ 3		46	A19
A1 ☐ 4		45	A18
B₁ 🛚 5		44 🏻	B18
B2 □ 6		43	B17
A2 🛚 7		42	A17
Аз 🛮 8		41	A16
B₃ □ 9		40	B16
B4 □ 10	48-Pin	39 🗖	B15
A4 ☐ 11	В	38	A15
GND ☐ 12		37	BE в
BEc □ 13		36	VCC
B₅ 🛘 14		35	B14
A5 ☐ 15		34	A14
A6 ☐ 16		33 🗖	A13
B6 ☐ 17		32	B13
B7 □ 18		31	B12
A7 🗖 19		30	A12
A8 □ 20		29	A11
B8 ☐ 21		28	B11
B9 ☐ 22		27	B10
A9 ☐ 23		26	A10
GND ☐ 24		25	BED

Product Pin Description

1

Pin Name	Description
$\overline{\text{BE}}$ x	Bus Enable Inputs (Active LOW)
A19-A0	Bus A
B19-B0	Bus B
GND	Ground
Vcc	Power



Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied40°C to +85°C
Supply Voltage to Ground Potential (Inputs & Vcc Only) –0.5V to +4.6V
Supply Voltage to Ground Potential (Outputs & D/O Only) . –0.5V to +4.6V
DC Input Voltage0.5V to +4.6V
DC Output Current
Power Dissipation

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics (Over the Operating Range, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 3.3\text{V} \pm 10\%$)

Parameters	Description	Test Conditions ⁽¹⁾	Min.	$Typ^{(2)}$	Max.	Units
V _{IH}	Input HIGH Voltage	Guaranteed Logic HIGH Level	2.0	_	_	V
V _{IL}	Input LOW Voltage	Guaranteed Logic LOW Level	-0.5	_	0.8	V
I_{IH}	Input HIGH Current	$V_{CC} = Max., V_{IN} = V_{CC}$	_	_	±1	μΑ
I_{IL}	Input LOW Current	V _{CC} = Max., V _{IN} = GND	_	_	±1	μΑ
I _{OZH}	High-Impedance Output Current	$0 \le A, B \le V_{CC}$	_	_	±1	μΑ
V _{IK}	Clamp Diode Voltage	$V_{CC} = Min., I_{IN} = -18mA$	_	_	-1.2	V
R _{ON}	Switch ON Resistance ⁽⁴⁾	$V_{CC} = Min., V_{IN} = 0.0V$ $Ion = 48mA \text{ or } 64mA$	_	5	8	Ω
		$V_{CC} = Min., V_{IN} = 2.4V$ $I_{ON} = 15mA$		10	17	Ω

Capacitance ($T_A = 25^{\circ}C$, f = 1 MHz)

Parameters ⁽⁵⁾	Description	Test Conditions	Тур	Max.	Units
C_{IN}	Input Capacitance	$V_{IN} = 0V$	_	3.0	pF
C _{OFF}	A/B Capacitance, Switch Off	$V_{IN} = 0V$	_	8.0	pF
Con	A/B Capacitance, Switch On	$V_{IN} = 0V$	_	16.0	pF

Notes:

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at $V_{CC} = 3.3V$, $T_A = 25$ °C ambient and maximum loading.
- 3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- 4. Measured by the voltage drop between A and B pin at indicated current through the switch. ON resistance is determined by the lower of the voltages on the two (A,B) pins.
- 5. This parameter is determined by device characterization but is not production tested.



Power Supply Characteristics

Para meters	Description	Test Conditions ⁽¹⁾	Min.	Typ ⁽²⁾	Max.	Units
I_{CC}	Quiescent Power Supply Current	$V_{CC} = Max., V_{IN} = GND \text{ or } V_{CC}$	_	0.1	3.0	μА
ΔI_{CC}	Supply Current per Input @ TTL HIGH	$V_{CC} = Max., V_{IN} = 3.0V^{(3)}$	_	_	750	μΑ

Notes:

- 1. For Max. or Min. conditons, use appropriate value specified under Electrical Characteristics for the applicable device.
- 2. Typical values are at $V_{CC} = 3.3V$, $+25^{\circ}C$ ambient.
- 3. Per TTL driven input (control inputs only); A and B pins do not contribute to I_{CC}.
- 4. This current applies to the control inputs only and represent the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is not tested, but is guaranteed by design.

PI3B32X384 Switching Characteristics over Operating Range

			PI3B32x384			
			C	om.		
Parameters	Description	Conditions (2,3)	Max.	Min.	Units	
t _{PLH} t _{PHL}	Propagation Delay ^(2,3) Ax to Bx, Bx to Ax	$C_L = 50 pF, R_L = 500 \Omega$		0.25		
t _{PZH}	Bus Enable Time BE to Ax or Bx	$C_L = 50 pF, R_L = 500 \Omega$	1.0	4.0	ns	
t _{PHZ}	Bus Disable Time BE to Ax or Bx	$R = 500\Omega$	1.0	3.5		

Notes:

- 1. See test circuit and waveforms.
- 2. This parameter is guaranteed but not tested on Propagation Delays.
- 3. The bus switch contributes no propagational delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns for 50pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagational delay to the system. Propagational delay of the bus switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

Ordering Information

Part	Pin - Package	Temperature
PI3B32X384B	48 - BQSOP (B)	−40°C to +85°C

Pericom Semiconductor Corporation

2380 Bering Drive • San Jose, CA 95131 • 1-800-435-2336 • Fax (408) 435-1100 • http://www.pericom.com